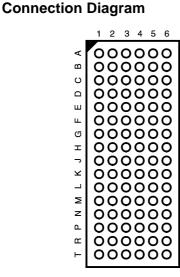


'4LCX32374 Low Voltage 32-Bit D-Type Flip-Flop with 5V Tolerant Inputs and Outputs (Preliminary)

74LCX32374



(Top Thru View)

Functional Description

The LCX32374 consists of thirty-two edge-triggered flip-flops with individual D-type inputs and 3-STATE true outputs. The device is byte controlled with each byte functioning identically, but independent of the other. The control pins can be shorted together to obtain full 32-bit operation. Each byte has a buffered clock and buffered Output Enable common to all flip-flops within that byte. The description which follows applies to each byte. Each flip-flop will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH Clock (CP_n) transition. With the Output Enable (\overline{OE}_n) LOW, the contents of the flip-flops are available at the outputs. When \overline{OE}_n is HIGH, the outputs go to the high impedance state. Operation of the \overline{OE}_n input does not affect the state of the flip-flops.

Pin Descriptions

Pin Names	Description
OEn	Output Enable Input (Active LOW)
CPn	Clock Pulse Input
I ₀ —I ₃₁	Inputs
O ₀ -O ₃₁	Outputs

FBGA Pin Assignments

	1	1	2	3	4	5	6
	Α	0 ₁	O ₀	OE ₁	CP ₁	I ₀	I ₁
	в	O ₃	0 ₂	GND	GND	l ₂	I ₃
	С	O ₅	O ₄	V _{CC}	V _{CC}	I_4	I ₅
	D	07	0 ₆	GND	GND	I ₆	I ₇
	Е	0 ₉	0 ₈	GND	GND	۱ ₈	l ₉
	F	0 ₁₁	O ₁₀	Vcc	V _{CC}	I ₁₀	I ₁₁
	G	0 ₁₃	0 ₁₂	GND	GND	I ₁₂	I ₁₃
	Н	O ₁₄	0 ₁₅	OE ₂	CP ₂	I ₁₅	I ₁₄
	2	O ₁₇	O ₁₆	OE ₃	CP ₃	I ₁₆	I ₁₇
2	ĸ	0 ₁₉	0 ₁₈	GND	GND	I ₁₈	I ₁₉
2	L	O ₂₁	O ₂₀	V _{CC}	V _{CC}	I ₂₀	I ₂₁
	M	023	O ₂₂	GND	GND	I ₂₂	I ₂₃
	N	O ₂₅	O ₂₄	GND	GND	I ₂₄	I ₂₅
	Р	0 ₂₇	0 ₂₆	V _{CC}	V _{CC}	I ₂₆	I ₂₇
	R	O ₂₉	O ₂₈	GND	GND	I ₂₈	I ₂₉
	Т	O ₃₀	O ₃₁	\overline{OE}_4	CP_4	I ₃₁	I ₃₀

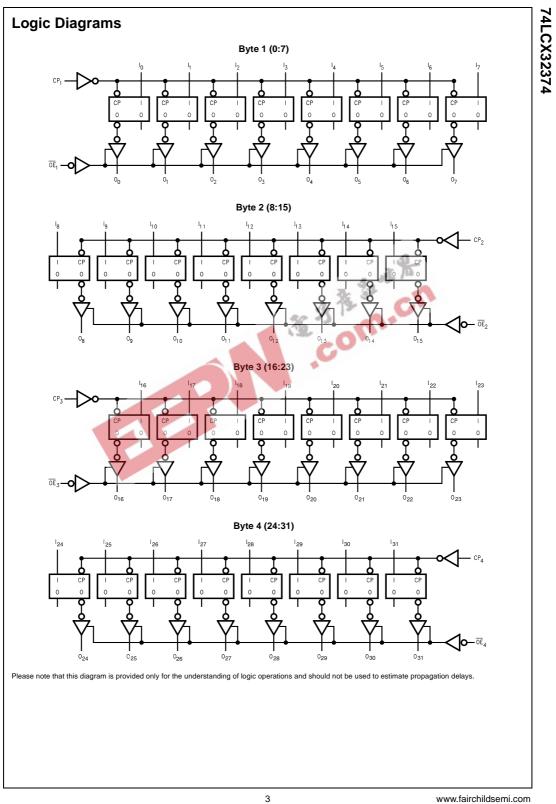
Truth Table

	Inputs		Outputs
CPn	OEn	I _n	O _n
~	L	Н	Н
~	L	L	L
L	L	Х	O ₀
х	Н	Х	Z

X = Immaterial

Z = High Impedance $O_0 = Previous O_0 before HIGH-to-LOW of CP$





74LCX32374

Symbol	Parameter	Value	Con	ditions		Units
Vcc	Supply Voltage	-0.5 to +7.0				V
/	DC Input Voltage	-0.5 to +7.0				V
/ ₀	DC Output Voltage	-0.5 to +7.0	3-STATE			
		-0.5 to V _{CC} + 0.5	Output in HIGH or L	OW State	(Note 4)	V
к	DC Input Diode Current	-50	V _I < GND			mA
ОК	DC Output Diode Current	-50	V _O < GND			
		+50	$V_{O} > V_{CC}$			mA
0	DC Output Source/Sink Current	±50				mA
СС	DC Supply Current per Supply Pin	±100				mA
GND	DC Ground Current per Ground Pin	±100				mA
Г _{STG}	Storage Temperature	-65 to +150				°C
Symbol	mmended Operating Co Para	ameter		Min	Max	Units
		ameter				Units
/cc	Supply Voltage		Operating	2.0	3.6	V
,	land the land		Data Retention	1.5	3.6	
/ ₁	Input Voltage	4		0	5.5	V
′o	Output Voltage	- 12 V	HGH or LOW State 3-STATE	0	V _{CC}	V
//	Output Current		$V_{\rm CC} = 3.0V - 3.6V$	0	5.5 ±24	
_{DH} /I _{OL}			$V_{CC} = 3.0V - 3.0V$ $V_{CC} = 2.7V - 3.0V$		±24 ±12	س ۸
			$V_{\rm CC} = 2.7V - 3.0V$ $V_{\rm CC} = 2.3V - 2.7V$		±12 ±8	mA
	Free-Air Operating Temperature		$v_{\rm CC} = 2.3 v - 2.7 v$	-40	±0 85	°C
Α .t/ΔV	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$, V_{CC}	- 3 0\/		-40	10	ns/V
-	Absolute Maximum Ratings are those values bey		device cannot be guarantee	÷	-	
at these lim	its. The parametric values defined in the Electrica	Characteristics tables are				
	erating Conditions" table will define the conditions bsolute Maximum Rating must be observed.	for actual device operation.				
-	ised inputs must be held HIGH or LOW. They may	not float				
	ectrical Characteristics					
			V _{cc}	T _A = -40	Т	
Symbol	Parameter	Conditions	(V)	Min	Max	Units
VIH	HIGH Level Input Voltage		2.3 – 2.7	1.7		
			2.7 - 3.6	2.0		V
V.	LOW Level Input Voltage		23-27	1	0.7	

Symbol	Parameter	Conditions	v _{cc}	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units
Symbol	Farameter	Conditions	(V)	Min	Max	Units
/ _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
/ _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	v
		2.7 - 3.6		0.8	v	
√ _{ОН}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2		
		I _{OH} = -8 mA	2.3	1.8		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		
		I _{OH} = -24 mA	3.0	2.2		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		I _{OL} = 8 mA	2.3		0.6	
		I _{OL} = 12 mA	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
I	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μA
OZ	3-STATE Output Leakage	$0 \le V_O \le 5.5V$	2.3 - 3.6		±5.0	μA
		$V_I = V_{IH} \text{ or } V_{IL}$				μΑ
OFF	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 V$	0	1	10	μΑ

DC Electrical Characteristics (Continued)									
Symbol	Parameter	Conditions	v _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units			
			(V)	Min	Max				
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		20	μA			
		$3.6V \le V_{I}, V_{O} \le 5.5V$ (Note 6)	2.3 - 3.6		±20	μΛ			
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μA			
Note 6: Outr	uts disabled or 3-STATE only			•		· · · · · · · · · · · · · · · · · · ·			

AC Electrical Characteristics

		$T_A = -40^\circ$ to $+85^\circ$ C, $R_L = 500\Omega$						
Symbol	Baramatar	V _{CC} = 3.	$3V \pm 0.3V$	$V_{CC} = 2.7V$		$V_{CC}=\textbf{2.5V}\pm\textbf{0.2V}$		Unite
	Parameter	C _L = 50 pF		C _L = 50 pF		C _L = 30 pF		Units
		Min	Max	Min	Max	Min	Max	
f _{MAX}	Maximum Clock Frequency	170						MHz
t _{PHL}	Propagation Delay	1.5	6.2	1.5	6.5	1.5	7.4	
t _{PLH}	CP to On	1.5	6.2	1.5	6.5	1.5	7.4	ns
t _{PZL}	Output Enable time	1.5	6.1	1.5	6.3 👞	1.5	7.9	ns
t _{PZH}		1.5	6.1	1.5	6.3	1.5	7.9	115
t _{PLZ}	Output Disable Time	1.5	6.0	1.5	6.2	1.5	7.2	ns
t _{PHZ}		1.5	6.0	1.5	6.2	1.5	7.2	115
t _S	Setup Time	2.5	18-1	2.5	1	3.0		ns
t _H	Hold Time	1.5		1.5		2.0		ns
t _W	Pulse Width	3.0		3.0		3.5		ns

Dynamic Switching Characteristics

		-			V _{cc}	T _A = 25°C	
Symbol	Parameter			Conditions	(V)	Typical	Units
V _{OLP}	Quiet Output Dynamic Peak VOL		$C_L = 50 \mu$	$F, V_{IH} = 3.3V, V_{IL} = 0V$	3.3	0.8	V
			$C_{L} = 30 \mu$	$PF, V_{IH} = 2.5V, V_{IL} = 0V$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley V _{OL}		$C_L = 50 \mu$	$PF, V_{IH} = 3.3V, V_{IL} = 0V$	3.3	-0.8	V
			$C_L = 30 \ \mu$	$PF, V_{IH} = 2.5V, V_{IL} = 0V$	2.5	0.6	v

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Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF

